

TABLE OF CONTENTS

Features	1	Absolute Maximum Ratings	5
Applications.....	1	ESD Caution.....	5
Functional Block Diagrams.....	1	Pin Configurations and Function Descriptions	6
General Description	1	Typical Performance Characteristics	7
Product Highlights	1	Terminology	9
Revision History	2	Test Circuits.....	10
Specifications.....	3	Outline Dimensions	11
Dual Supply	3	Ordering Guide	12
Single Supply	4		

REVISION HISTORY

3/15—Rev. C to Rev. D

Changes to IR Reflow, Peak Temperature Parameter, Table 4	5
Updated Outline Dimensions	11
Changes to Ordering Guide	12

3/07—Rev. B to Rev. C

Added Die Package.....	Universal
Changes to Specifications	3
Added Figure 4 and Table 6.....	6
Changes to Ordering Guide	11

3/06—Rev. A to Rev. B

Updated Format.....	Universal
Changes to 6-Lead SOT-23 (RJ-6) Pin Configuration	6
Added Pin Function Descriptions Table	6
Changes to Figure 19.....	9
Updated Outline Dimensions.....	11
Changes to Ordering Guide	11

6/03—Rev. 0 to Rev. A

Changes to Specifications.....	2
Changes to Ordering Guide	4
Updated Outline Dimensions.....	8

11/01—Revision 0: Initial Version

SPECIFICATIONS

DUAL SUPPLY

$V_{DD} = 5\text{ V} \pm 10\%$, $V_{SS} = -5\text{ V} \pm 10\%$, $GND = 0\text{ V}$, unless otherwise noted.

Table 2.

Parameter	B Version ¹		Unit	Test Conditions/Comments
	+25°C	−40°C to +85°C		
ANALOG SWITCH				
Analog Signal Range		V_{SS} to V_{DD}	V	$V_{DD} = +4.5\text{ V}$, $V_{SS} = -4.5\text{ V}$
On Resistance (R_{ON})	2		Ω typ	$V_S = \pm 4.5\text{ V}$, $I_{DS} = -10\text{ mA}$; see Figure 15
	2.5	5.5	Ω max	
On-Resistance Flatness ($R_{FLAT(ON)}$)	0.35	0.4	Ω typ	$V_S = \pm 3.3\text{ V}$, $I_{DS} = -10\text{ mA}$
	0.6	0.65	Ω max	
LEAKAGE CURRENTS				$V_{DD} = +5.5\text{ V}$, $V_{SS} = -5.5\text{ V}$
Source Off Leakage, I_S (Off)	± 0.01	± 1	nA typ	$V_S = +4.5\text{ V}/-4.5\text{ V}$, $V_D = -4.5\text{ V}/+4.5\text{ V}$; see Figure 16
	± 0.25		nA max	
Drain Off Leakage, I_D (Off)	± 0.01	± 1	nA typ	$V_S = +4.5\text{ V}/-4.5\text{ V}$, $V_D = -4.5\text{ V}/+4.5\text{ V}$; see Figure 16
	± 0.25		nA max	
Channel On Leakage, I_D , I_S (On)	± 0.01	± 1	nA typ	$V_S = V_D = +4.5\text{ V}$ or -4.5 V ; see Figure 17
	± 0.25		nA max	
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.4	V min	$V_{IN} = V_{INL}$ or V_{INH}
Input Low Voltage, V_{INL}		0.8	V max	
Input Current, I_{INL} or I_{INH}	0.005	± 0.1	μA typ	
			μA max	
Digital Input Capacitance, C_{IN}	2		pF typ	
DYNAMIC CHARACTERISTICS ²				
t_{ON}	80	155	ns typ	$R_L = 300\ \Omega$, $C_L = 35\text{ pF}$
	120		ns max	$V_S = 3.3\text{ V}$; see Figure 18
t_{OFF}	45	90	ns typ	$R_L = 300\ \Omega$, $C_L = 35\text{ pF}$
	75		ns max	$V_S = 3.3\text{ V}$; see Figure 18
Charge Injection	250		pC typ	$V_S = 0\text{ V}$, $R_S = 0\ \Omega$, $C_L = 1\text{ nF}$; see Figure 19
Off Isolation	−60		dB typ	$R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; see Figure 20
Bandwidth −3 dB	180		MHz typ	$R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; see Figure 21
C_S (Off)	50		pF typ	$f = 1\text{ MHz}$
C_D (Off)	50		pF typ	$f = 1\text{ MHz}$
C_D , C_S (On)	145		pF typ	$f = 1\text{ MHz}$
POWER REQUIREMENTS				$V_{DD} = +5.5\text{ V}$, $V_{SS} = -5.5\text{ V}$
I_{DD}	0.001	1.0	μA typ	Digital inputs = 0 V or 5.5 V
			μA max	
I_{SS}	0.001	1.0	μA typ	Digital inputs = 0 V or 5.5 V
			μA max	

¹ Temperature range for B version is −40°C to +85°C.

² Guaranteed by design, not subject to production test.

SINGLE SUPPLY

$V_{DD} = 5\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.

Table 3.

Parameter	B Version ¹		Unit	Test Conditions/Comments
	+25°C	–40°C to +85°C		
ANALOG SWITCH				
Analog Signal Range		0 V to V _{DD}	V	V _{DD} = 4.5 V
On Resistance (R _{ON})	3.5		Ω typ	V _S = 0 V to 4.5 V, I _{DS} = –10 mA; see Figure 15
	5	8	Ω max	
On-Resistance Flatness (R _{FLAT (ON)})	0.2	0.2	Ω typ	V _S = 1.5 V to 3.3 V, I _{DS} = –10 mA
		0.6	Ω max	
LEAKAGE CURRENTS				
Source Off Leakage, I _S (Off)	±0.01		nA typ	V _{DD} = 5.5 V
	±0.25	±1	nA max	V _S = 4.5 V/1 V, V _D = 1 V/4.5 V; see Figure 16
Drain Off Leakage, I _D (Off)	±0.01		nA typ	V _S = 4.5 V/1 V, V _D = 1 V/4.5 V; see Figure 16
	±0.25	±1	nA max	
Channel On Leakage, I _D , I _S (On)	±0.01		nA typ	V _S = V _D = 4.5 V or 1 V; see Figure 17
	±0.25	±1	nA max	
DIGITAL INPUTS				
Input High Voltage, V _{INH}		2.4	V min	V _{IN} = V _{INL} or V _{INH}
Input Low Voltage, V _{INL}		0.8	V max	
Input Current, I _{INL} or I _{INH}	0.005		μA typ	
		±0.1	μA max	
Digital Input Capacitance, C _{IN}	2		pF typ	
DYNAMIC CHARACTERISTICS ²				
t _{ON}	110		ns typ	R _L = 300 Ω, C _L = 35 pF
	220	280	ns max	V _S = 3.3 V; see Figure 18
t _{OFF}	50		ns typ	R _L = 300 Ω, C _L = 35 pF
	80	110	ns max	V _S = 3.3 V; see Figure 18
Charge Injection	20		pC typ	V _S = 0 V, R _S = 0 Ω, C _L = 1 nF; see Figure 19
Off Isolation	–60		dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 20
Bandwidth –3 dB	180		MHz typ	R _L = 50 Ω, C _L = 5 pF; see Figure 21
C _S (Off)	50		pF typ	f = 1 MHz
C _D (Off)	50		pF typ	f = 1 MHz
C _D , C _S (On)	145		pF typ	f = 1 MHz
POWER REQUIREMENTS				
I _{DD}	0.001		μA typ	V _{DD} = 5.5 V
		1.0	μA max	Digital inputs = 0 V or 5.5 V

¹ Temperature range for B version is –40°C to +85°C.

² Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 4.

Parameter	Rating
V_{DD} to V_{SS}	13 V
V_{DD} to GND	−0.3 V to +6.5 V
V_{SS} to GND	+0.3 V to −6.5 V
Analog Inputs ¹	$V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$
Digital Inputs ¹	−0.3 V to $V_{DD} + 0.3\text{ V}$ or 30 mA (whichever occurs first)
Continuous Current, S or D	100 mA
Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle Max)	200 mA
Operating Temperature Range	
Industrial (B Version)	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
Thermal Resistance	
MSOP	
θ_{JA}	206°C/W
θ_{JC}	44°C/W
SOT-23	
θ_{JA}	229.6°C/W
θ_{JC}	91.99°C/W
Lead Temperature, Soldering (10 sec)	300°C
IR Reflow, Peak Temperature	260°C

¹ Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating may be applied at a time.

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

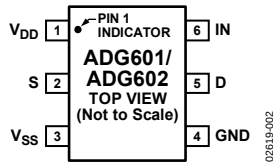


Figure 2. 6-Lead SOT-23 (RJ-6)

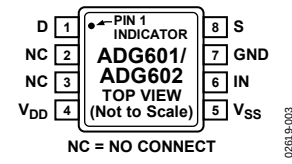
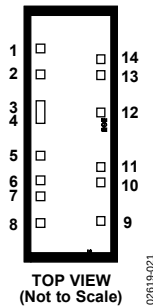


Figure 3. 8-Lead MSOP (RM-8)

Table 5. Pin Function Descriptions

Pin No.		Mnemonic	Description
6-Lead SOT-23	8-Lead MSOP		
1	4	V _{DD}	Most Positive Power Supply Potential.
2	8	S	Source Terminal. Can be an input or output.
3	5	V _{SS}	Most Negative Power Supply Potential.
4	7	GND	Ground (0 V) Reference.
5	1	D	Drain Terminal. Can be an input or output.
6	6	IN	Logic Control Input.
N/A ¹	2, 3	NC	No Connect.

¹ N/A is not applicable.Figure 4. Die (820 μm $\times$ 2255 μm)Table 6. Die Pad Coordinates¹

Die Pad No.	Die Pad Coordinates		Mnemonic	Description
	X (μm)	Y (μm)		
1	-265	+754	NC	No Connect.
2	-265	+525	D	Drain Terminal. Can be an input or output. ²
3	-265	+241	D	Drain Terminal. Can be an input or output. ²
4	-265	+141	D	Drain Terminal. Can be an input or output. ²
5	-265	-191	NC	No Connect.
6	-265	-409	NC	No Connect.
7	-265	-549	NC	No Connect.
8	-265	-787	V _{DD}	Most Positive Power Supply Potential.
9	+265	-767	V _{SS}	Most Negative Power Supply Potential.
10	+265	-429	IN	Logic Control Input.
11	+265	-289	GND	Ground (0 V) Reference.
12	+265	+189	S	Source Terminal. Can be an input or output. ³
13	+265	+521	S	Source Terminal. Can be an input or output. ³
14	+265	+661	NC	Source Terminal. Can be an input or output.

¹ Measured from the center of the die.² Bond the D pads together to a single point to preserve the on resistance and current handling capability. The common point acts as the drain pin of the switch.³ Bond the S pads together to a single point to preserve the on resistance and current handling capability. The common point acts as the source pin of the switch.

TYPICAL PERFORMANCE CHARACTERISTICS

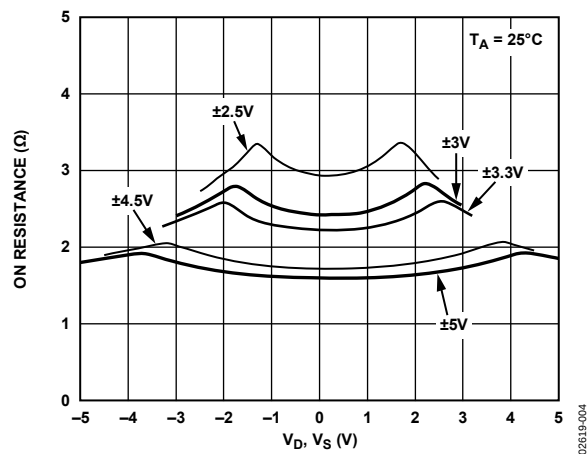
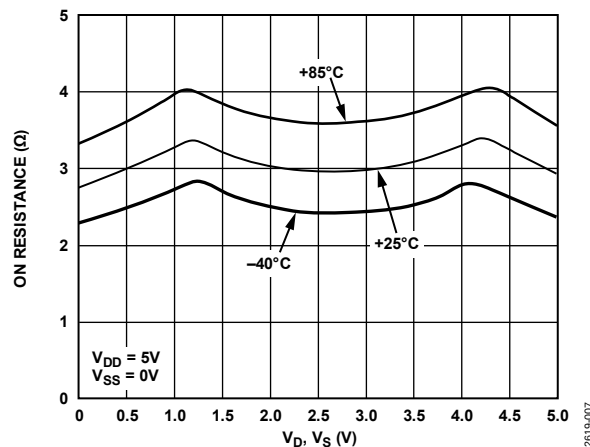
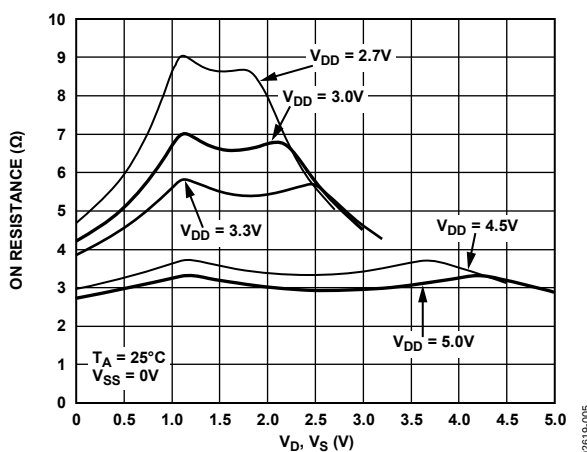
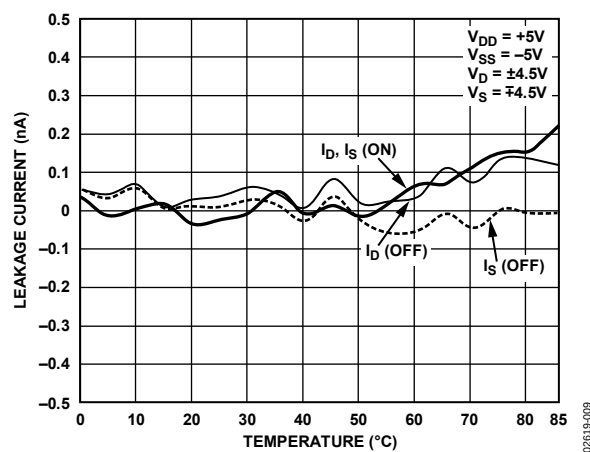
Figure 5. On Resistance vs. V_D, V_S (Dual Supply)Figure 8. On Resistance vs. V_D, V_S for Different Temperatures (Single Supply)Figure 6. On Resistance vs. V_D, V_S (Single Supply)

Figure 9. Leakage Currents vs. Temperature (Dual Supply)

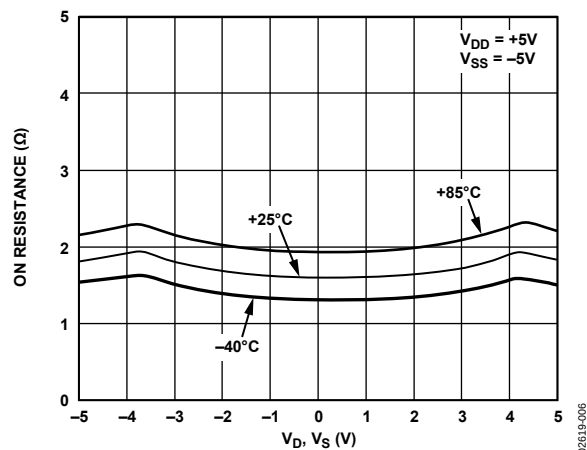
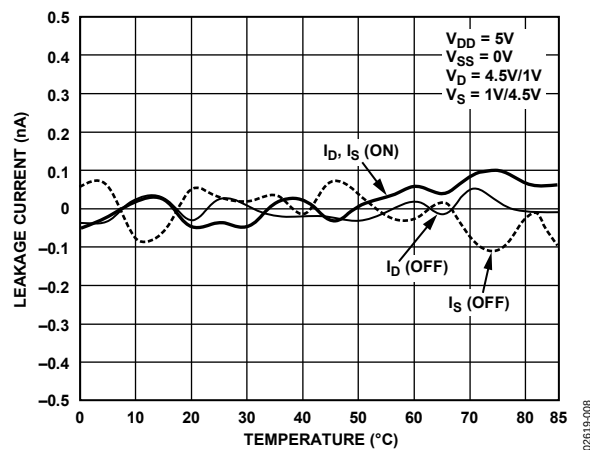
Figure 7. On Resistance vs. V_D, V_S for Different Temperatures (Dual Supply)

Figure 10. Leakage Currents vs. Temperature (Single Supply)

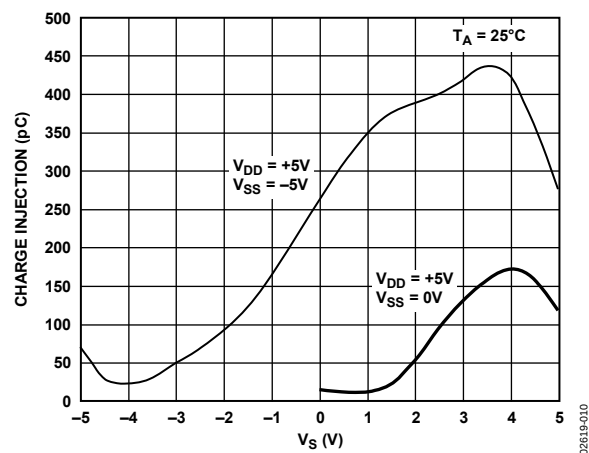


Figure 11. Charge Injection vs. Source Voltage

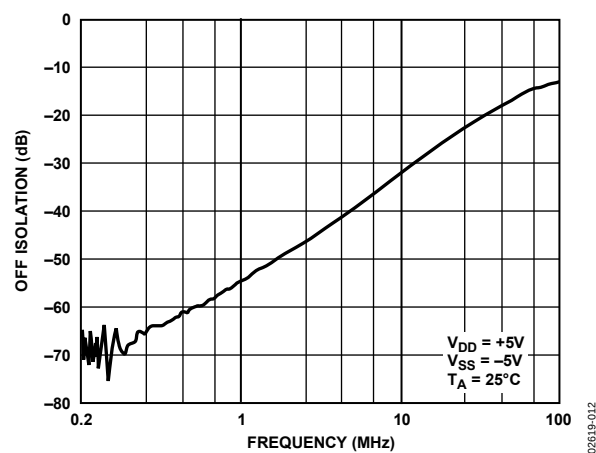


Figure 13. Off Isolation vs. Frequency

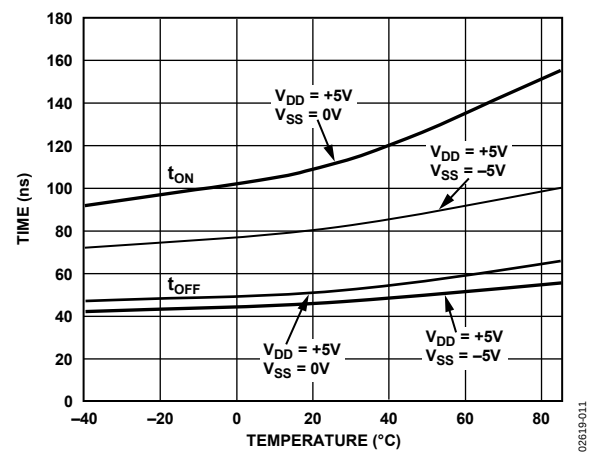


Figure 12. t_{ON}/t_{OFF} Times vs. Temperature

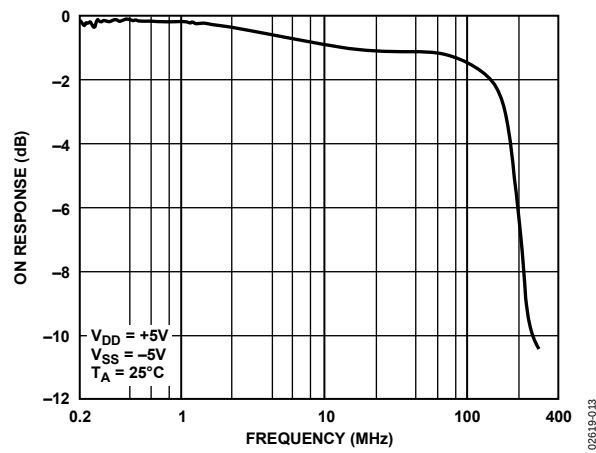


Figure 14. On Response vs. Frequency

TERMINOLOGY

V_{DD}

Most positive power supply potential.

V_{SS}

Most negative power supply potential.

I_{DD}

Positive supply current.

I_{SS}

Negative supply current.

GND

Ground (0 V) reference.

S

Source terminal. Can be an input or an output.

D

Drain terminal. Can be an input or an output.

IN

Logic control input.

V_D, V_S

Analog voltage on Terminal D and Terminal S.

R_{ON}

Ohmic resistance between Terminal D and Terminal S.

R_{FLAT} (ON)

Flatness is defined as the difference between the maximum and minimum values of on resistance as measured over the specified analog signal range.

I_S (Off)

Source leakage current with the switch off.

I_D (Off)

Drain leakage current with the switch off.

I_D, I_S (On)

Channel leakage current with the switch on.

V_{INL}

Maximum input voltage for Logic 0.

V_{INH}

Minimum input voltage for Logic 1.

I_{INL} (I_{INH})

Input current of the digital input.

C_S (Off)

Off switch source capacitance. Measured with reference to ground.

C_D (Off)

Off switch drain capacitance. Measured with reference to ground.

C_D, C_S (On)

On switch capacitance. Measured with reference to ground.

C_{IN}

Digital input capacitance.

t_{ON}

Delay between applying the digital control input and the output switching on.

t_{OFF}

Delay between applying the digital control input and the output switching off.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

Off Isolation

A measure of unwanted signal coupling through an off switch.

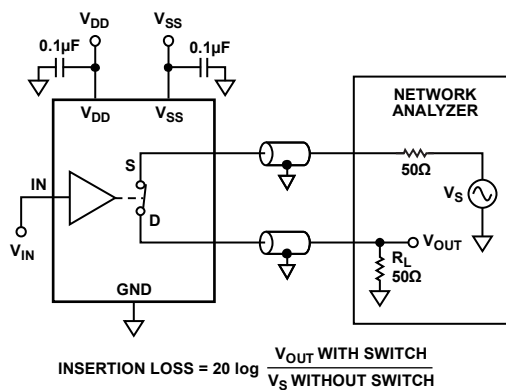
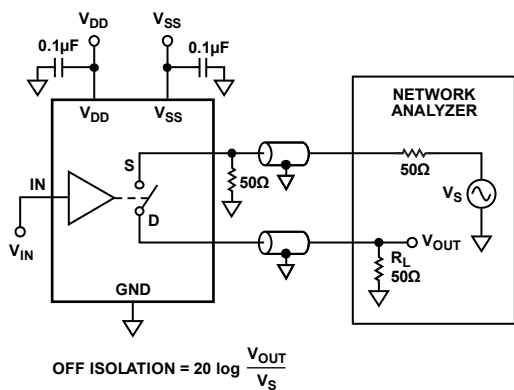
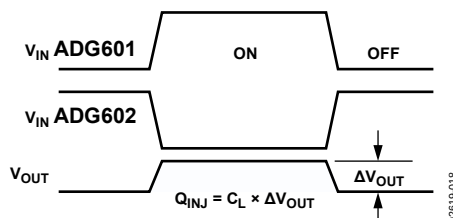
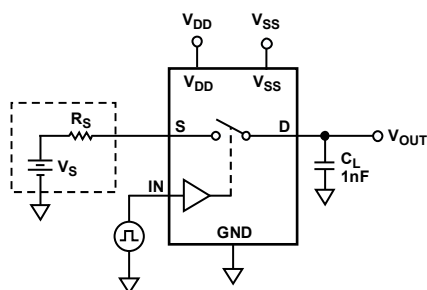
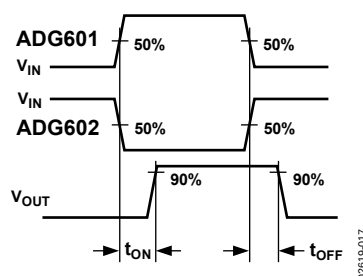
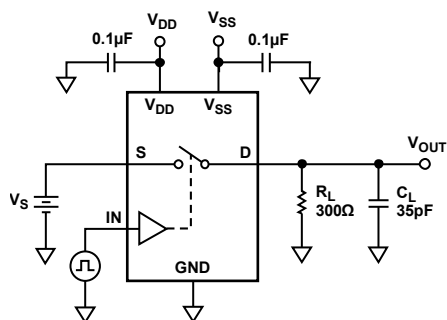
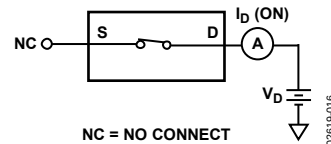
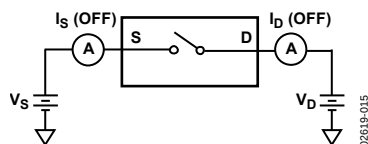
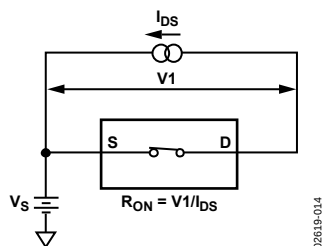
On Response

Frequency response of the on switch.

Insertion Loss

Loss due to the on resistance of the switch.

TEST CIRCUITS



OUTLINE DIMENSIONS

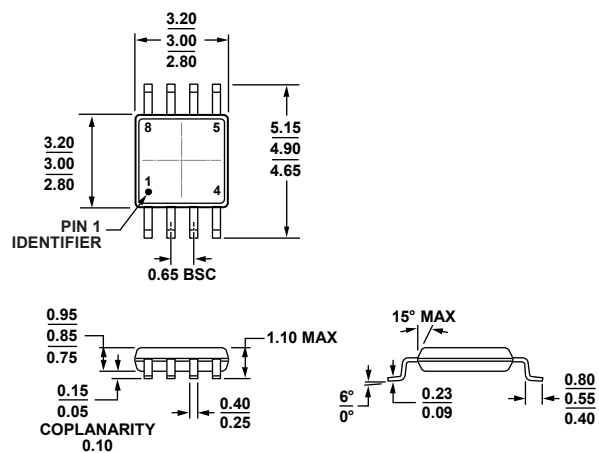


Figure 22. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)

Dimensions shown in millimeters

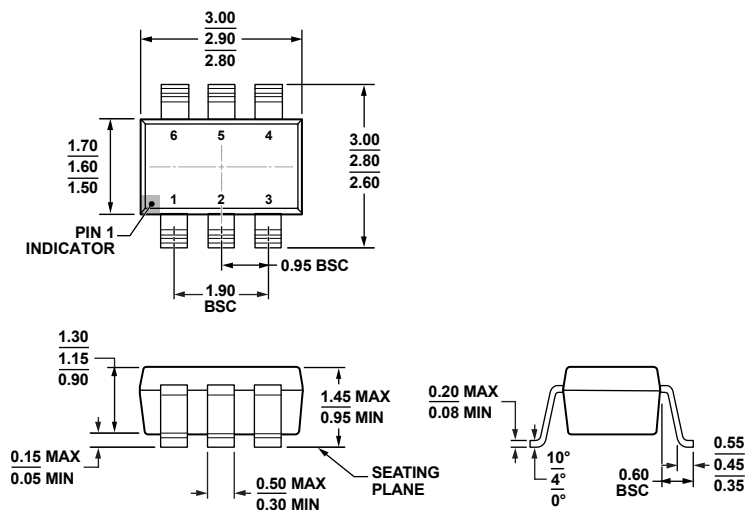


Figure 23. 6-Lead Small Outline Transistor Package [SOT-23]
(RJ-6)

Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Branding ²
ADG601BRTZ-REEL	–40°C to +85°C	6-Lead SOT-23	RJ-6	STB#
ADG601BRTZ-REEL7	–40°C to +85°C	6-Lead SOT-23	RJ-6	STB#
ADG601BRMZ	–40°C to +85°C	8-Lead MSOP	RM-8	S1G
ADG601BRMZ-REEL7	–40°C to +85°C	8-Lead MSOP	RM-8	S1G
ADG601C-PT7		Die		
ADG602BRTZ-REEL7	–40°C to +85°C	6-Lead SOT-23	RJ-6	S18
ADG602BRMZ	–40°C to +85°C	8-Lead MSOP	RM-8	S18
ADG602BRMZ-REEL7	–40°C to +85°C	8-Lead MSOP	RM-8	S18

¹ Z = RoHS Compliant Part, # denotes RoHS compliant product, may be top or bottom marked.

² Branding on SOT-23 and MSOP is limited to three characters due to space constraints.